

View Online at <https://aerobasegroup.com/nsn/5961-00-264-5058>

Inclosure Material:

Metal or plastic

Overall Length:

Between 0.240 inches and 0.275 inches

Overall Height:

Between 0.030 inches and 0.080 inches

Overall Width:

Between 0.140 inches and 0.260 inches

Component Name And Quantity:

4 transistor

Mounting Method:

Press fit

Features Provided:

Burn in and hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

40.0 collector to emitter voltage, dc all transistor and 75.0 collector to base voltage, dc all transistor and 6.0 emitter to base voltage, dc all transistor

Current Rating Per Characteristic:

600.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector absolute all transistor

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

All transistor junction pattern arrangement: npn

Terminal Type And Quantity:

14 ribbon

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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